



JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

SOD-323 Plastic-Encapsulate Diodes

BAT42WS/BAT43WS SCHOTTKY DIODES

FEATURES

- Low Forward Voltage Drop
- Fast Switching Time
- Surface Mount Package Ideally Suited for Automatic Insertion
- Also Available in Lead Free Version

MARKING: BAT42WS S7
BAT43WS S8



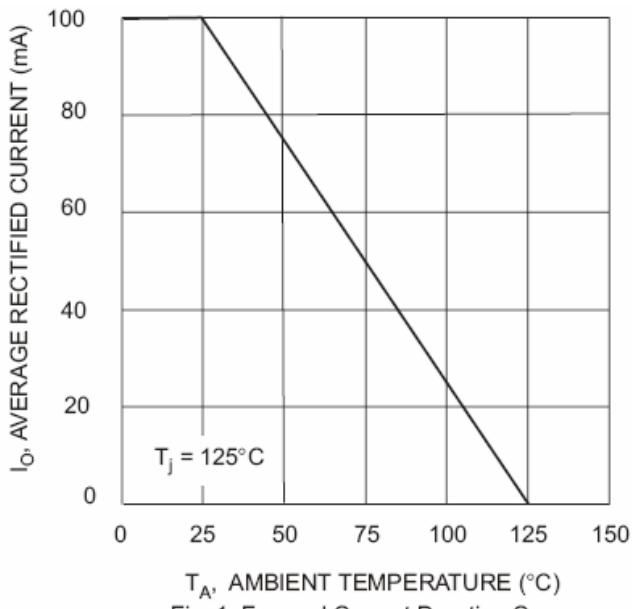
Maximum Ratings and Electrical Characteristics, Single Diode @T_A=25°C

Parameter	Symbol	BAT42WS/BAT43WS		Unit
Peak Repetitive Peak reverse voltage	V _{RRM}			
Working Peak Voltage	V _{RWM}	30		V
DC Blocking Voltage	V _R			
RMS Reverse Voltage	V _{R(RMS)}	21		V
Forward Continuous Current	I _{FM}	200		mA
Repetitive Peak Forward Current@t<1.0s	I _{FRM}	500		mA
Peak forward surge current @<10ms	I _{FSM}	4.0		A
Power Dissipation	P _d	200		mW
Thermal Resistance Junction to Ambient	R _{θJA}	625		K/W
Storage temperature	T _{STG}	-55~+125		°C

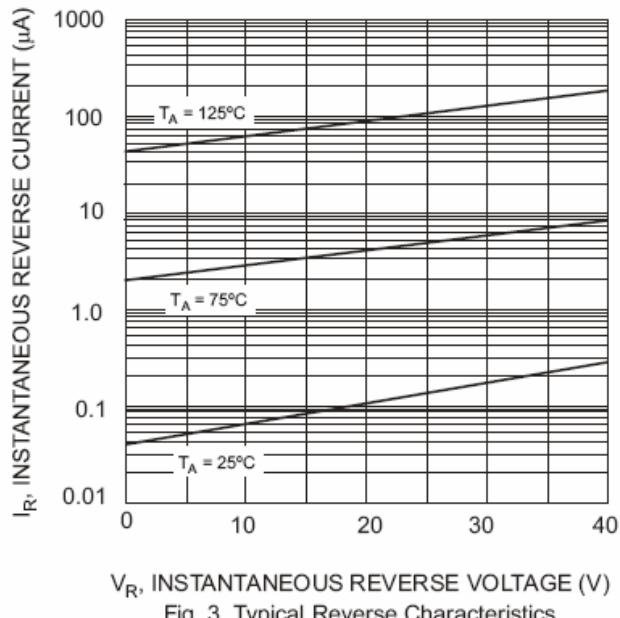
Electrical Ratings @T_A=25°C

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Reverse Breakdown Voltage	V _{(BR)R}	30			V	IR=100μA
Forward voltage	V _F			1.0	V	I _F =200mA
	V _F			0.4	V	I _F =10mA
	V _F			0.65	V	I _F =50mA
	V _F	0.26		0.33	V	I _F =2mA
	V _F			0.45	V	I _F =15mA
Reverse current	I _R			0.5	μA	V _R =25V
Capacitance between terminals	C _T			10	pF	V _R =1.0V,f=1.0MHz
Reverse Recovery Time	t _{rr}			5	ns	I _F =I _R =10mA I _{rr} =0.1XI _R ,R _L =100Ω

Typical Characteristics

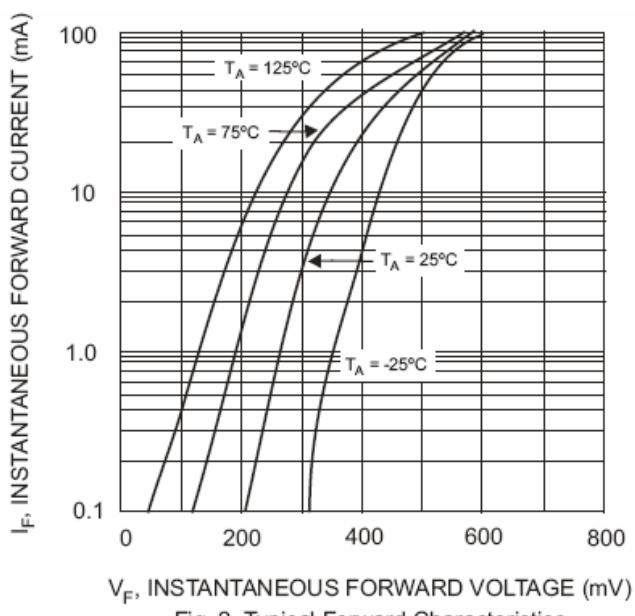


T_A , AMBIENT TEMPERATURE (°C)
Fig. 1 Forward Current Derating Curve

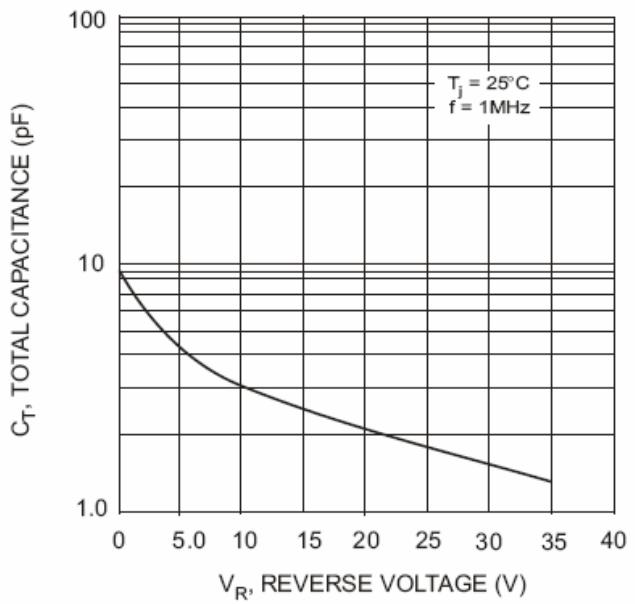


V_R , INSTANTANEOUS REVERSE VOLTAGE (V)
Fig. 3 Typical Reverse Characteristics

BAT42WS/BAT43WS



V_F , INSTANTANEOUS FORWARD VOLTAGE (mV)
Fig. 2 Typical Forward Characteristics



V_R , REVERSE VOLTAGE (V)
Fig. 4 Total Capacitance vs. Reverse Voltage